

Pch -30V -14A Power MOSFET

V_{DSS}	-30V
R _{DS(on)} (Max.)	7m Ω
I _D	-14A
P_D	2.0W

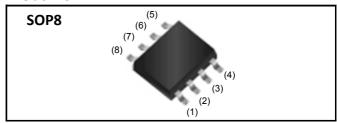
Features

- 1) Low on resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small Surface Mount Package (SOP8).
- 4) Pb-free lead plating; RoHS compliant

Application

DC/DC Converter

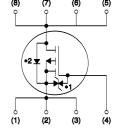
●Outline



•Inner circuit

- (1) Source (2) Source
- (5) Drain (6) Drain
- (3) Source (4) Gate
- (7) Drain (8) Drain





Packaging specifications

	Packaging	Taping
	Reel size (mm)	330
Typo	Tape width (mm)	12
Туре	Basic ordering unit (pcs)	2,500
	Taping code	ТВ
	Marking	RRH140P03

●Absolute maximum ratings(T_a = 25°C)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V_{DSS}	-30	V
Continuous drain current	I _D *1	±14	А
Pulsed drain current	I _{D,pulse} *2	±56	А
Gate - Source voltage	V_{GSS}	±20	V
Avalanche energy, single pulse	E _{AS} *3	1.6	mJ
Dower discipation	P _D *4	2.0	W
Power dissipation	P _D *5	0.65	W
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	-55 to +150	°C

Datasheet

●Thermal resistance

Parameter	Symbol		Values		Unit
- Farametei	Зуппоп	Min.	Тур.	Max.	Offic
Thermal resistance, junction - ambient	R _{thJA} *4	-	-	62.5	°C/W
Thermal resistance, junction - ambient	R _{thJA} *5	-	-	192	°C/W

•Electrical characteristics($T_a = 25$ °C)

Parameter	Symbol	Conditions	Values			Unit	
r ai ai ii etei	Symbol	Conditions	Min.	Тур.	Max.	Offic	
Drain - Source breakdown voltage	V _{(BR)DSS}	V_{GS} = 0V, I_D = -1 mA	-30	-	-	V	
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$	I _D = -1mA referenced to 25°C	1	-25	-	mV/°C	
Zero gate voltage drain current	I _{DSS}	$V_{DS} = -30V, V_{GS} = 0V$	ı	-	-1	μА	
Gate - Source leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±10	μА	
Gate threshold voltage	V _{GS (th)}	$V_{DS} = -10V, I_{D} = -1mA$	-1.0	ı	-2.5	V	
Gate threshold voltage temperature coefficient	$\frac{\Delta V_{(GS)th}}{\Delta T_{j}}$	I _D = -1mA referenced to 25°C	-	3.9	-	mV/°C	
		V _{GS} =-10V, I _D =-14A	-	5.0	7.0		
Static drain - source	D *6	V _{GS} =-4.5V, I _D =-7A	-	6.7	9.4	mO	
on - state resistance	$R_{DS(on)}$	V _{GS} =-4.0V, I _D =-7A	-	7.3	10.2	mΩ	
		V _{GS} = -10V, I _D = -14A, T _j =125°C	ı	7.5	10.5		
Gate input resistannce	R_{G}	f = 1MHz, open drain	-	3.0	-	Ω	
Transconductance	9 fs *6	$V_{DS} = -10V, I_{D} = -14A$	20	40	-	S	

^{*1} Limited only by maximum temperature allowed.

^{*2} Pw \leq 10 $\mu s,~Duty~cycle \leq$ 1%

^{*3} L \simeq 10 μ H, V_{DD} = -15V, Rg = 25 Ω , starting T_i = 25 $^{\circ}$ C

^{*4} Mounted on a ceramic board (30×30×0.8mm)

^{*5} Mounted on a FR4 (20×20×0.8mm)

Datasheet

●Electrical characteristics(T_a = 25°C)

Parameter	Symbol	Conditions		Unit		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Input capacitance	C _{iss}	V _{GS} = 0V	-	8000	-	
Output capacitance	C _{oss}	V _{DS} = -10V	-	1000	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	1000	-	
Turn - on delay time	t _{d(on)} *6	$V_{DD} \simeq -15V$, $V_{GS} = -10V$	-	32	-	
Rise time	t _r *6	I _D = -7A	-	80	-	no
Turn - off delay time	${\rm t_{d(off)}}^{*6}$	$R_L = 2.1\Omega$	-	360	-	ns
Fall time	t _f *6	$R_G = 10\Omega$	-	200	-	

•Gate Charge characteristics($T_a = 25$ °C)

Parameter	Symbol	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Total gate charge	Q_g^{*6}	$V_{DD} = -15V, I_D = -14A$ $V_{GS} = -5V$	-	80	1	
Total gate charge		$V_{DD}^{\sim} -15V, I_{D} = -14A$ $V_{GS} = -10V$	-	150	-	nC
Gate - Source charge	Q _{gs} *6	$V_{DD}^{2} - 15V, I_{D} = -14A$ $V_{GS} = -5V$	-	18	-	
Gate - Drain charge	Q _{gd} *6	$V_{GS} = -5V$	-	30	-	

●Body diode electrical characteristics (Source-Drain)(T_a = 25°C)

Parameter	Symbol Conditions	Conditions	Values			Unit	
r arameter	Symbol Conditions –		Min.	Тур.	Max.	Offic	
Inverse diode continuous, forward current	l _S *1	T _a = 25°C	-	ı	-1.6	А	
Forward voltage	V _{SD} *6	$V_{GS} = 0V, I_{s} = -14A$	1	1	-1.2	V	
Reverse recovery time	t _{rr} *6	I _S = -14A	1	50	100	ns	
Reverse recovery charge	Q _{rr} *6	di/dt = 100A / μs	-	50	100	μС	

^{*6} Pulsed



•Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

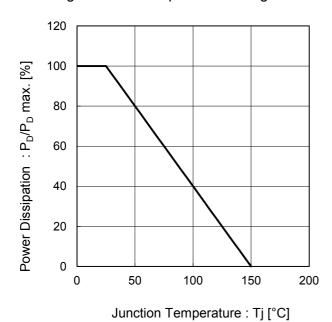
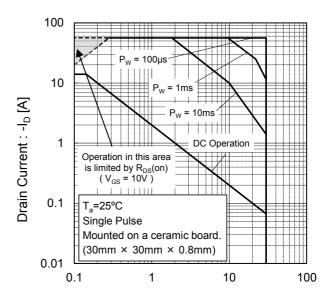
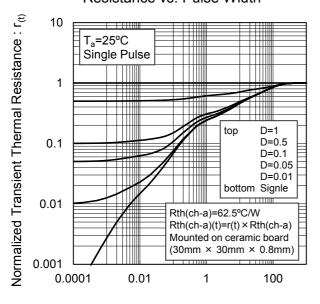


Fig.2 Maximum Safe Operating Area



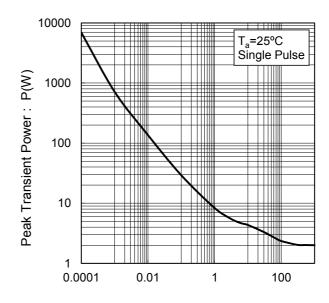
Drain - Source Voltage : -V_{DS} [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



Pulse Width: Pw [s]

Fig.4 Single Pulse Maxmum Power dissipation



Pulse Width: Pw [s]

•Electrical characteristic curves

Fig.5 Avalanche Current vs Inductive Load

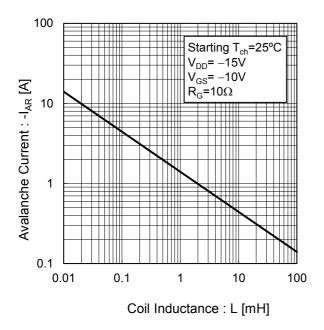
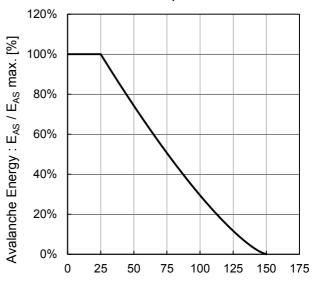


Fig.6 Avalanche Energy Derating Curve vs Junction Temperature



Junction Temperature : T_i [°C]

Fig.7 Typical Output Characteristics(I)

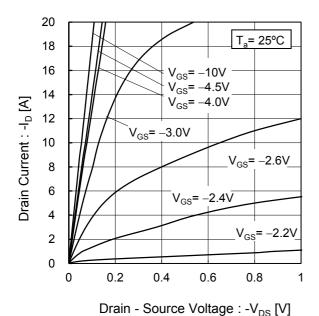
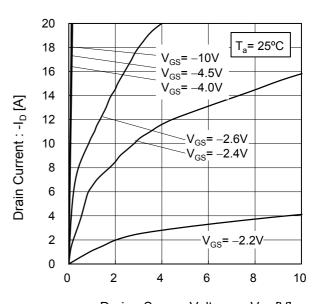


Fig.8 Typical Output Characteristics(II)



Drain - Source Voltage : -V_{DS} [V]

•Electrical characteristic curves

Fig.9 Breakdown Voltage
vs. Junction Temperature

V_{GS}=0V
I_D= -1mA

20
-50
0
50
100
150

Fig.10 Typical Transfer Characteristics

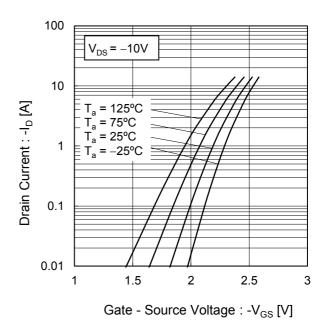


Fig.11 Gate Threshold Voltage vs. Junction Temperature

Junction Temperature : T_i [°C]

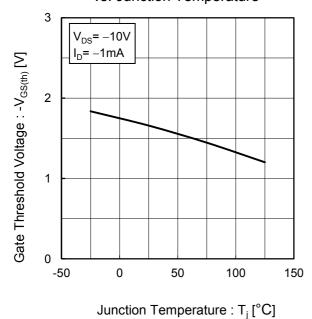
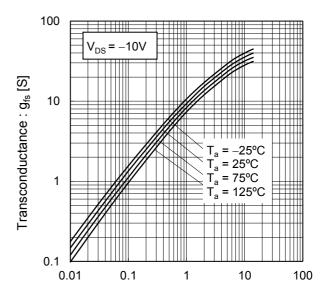


Fig.12 Transconductance vs. Drain Current



•Electrical characteristic curves

Fig.13 Drain Current Derating Curve

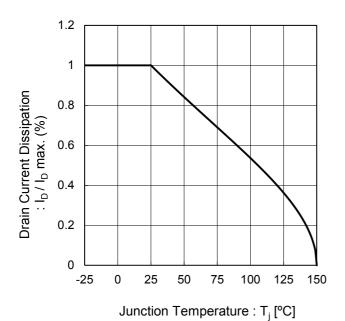
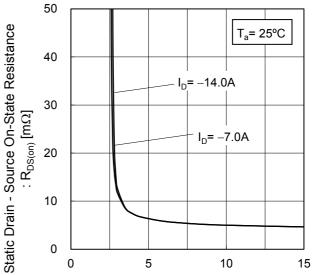


Fig.14 Static Drain - Source On - State Resistance vs. Gate Source Voltage



Gate - Source Voltage : -V_{GS} [V]

Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(I)

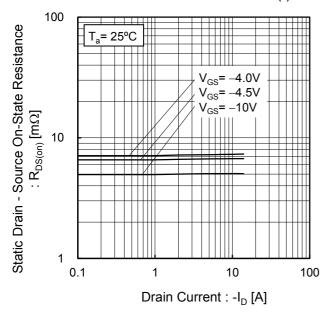
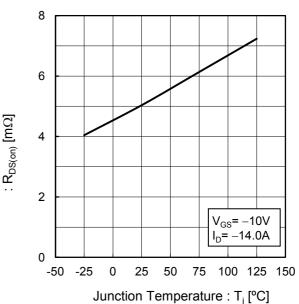


Fig.16 Static Drain - Source On - State Resistance vs. Junction Temperature



Static Drain - Source On-State Resistance

•Electrical characteristic curves

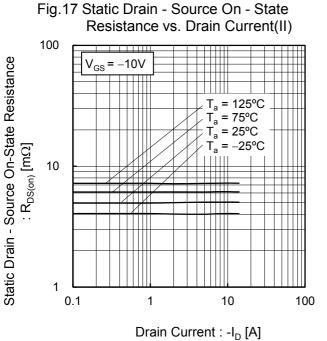
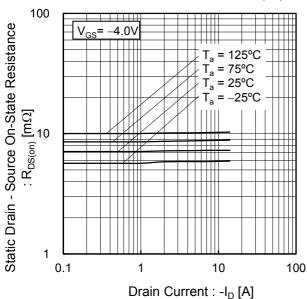


Fig.18 Static Drain - Source On - State
Resistance vs. Drain Current(III)

To Drain Current: -I_D [A]

Fig.19 Static Drain - Source On - State Resistance vs. Drain Current(IV)



•Electrical characteristic curves

Fig.20 Typical Capacitance vs. Drain - Source Voltage

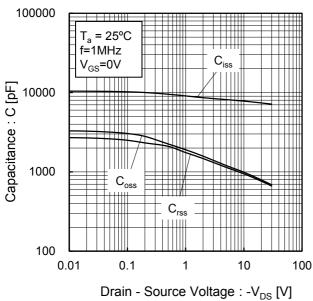


Fig.21 Switching Characteristics

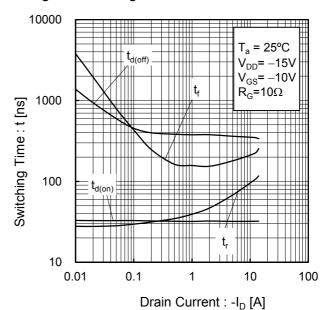


Fig.22 Dynamic Input Characteristics

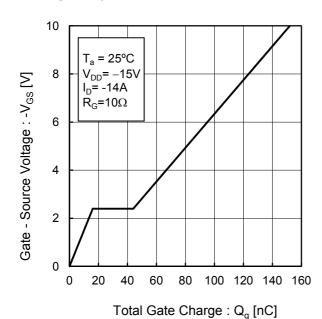
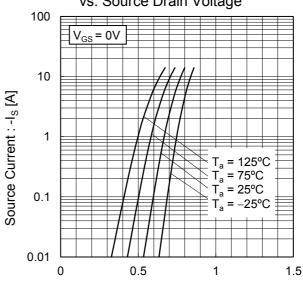


Fig.23 Source Current vs. Source Drain Voltage



Source-Drain Voltage : -V_{DS} [V]

Datasheet **RRH140P03**

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

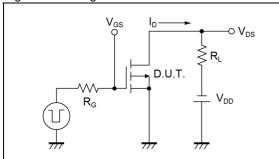


Fig.2-1 Gate Charge Measurement Circuit

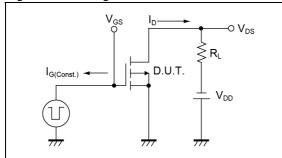


Fig.3-1 Avalanche Measurement Circuit

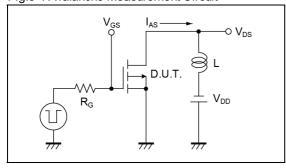


Fig.1-2 Switching Waveforms

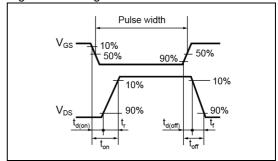


Fig.2-2 Gate Charge Waveform

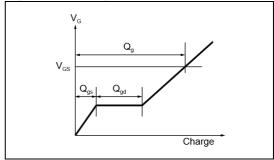
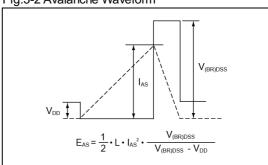
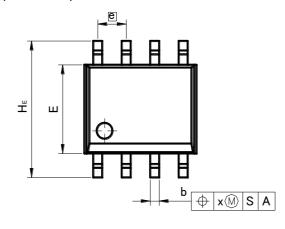


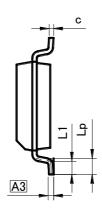
Fig.3-2 Avalanche Waveform

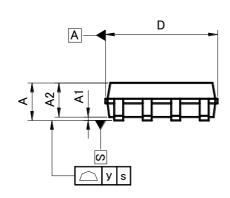


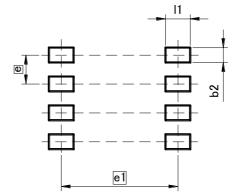
●Dimensions (Unit : mm)











Patterm of terminal position areas

DIM	MILIMI	ETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	-	1.75	_	0.069	
A1	0.	15	0.0	006	
A2	1.40	1.60	0.055	0.063	
A3	0.2	25	0.0	01	
b	0.30	0.50	0.012	0.02	
С	0.10	0.30	0.004	0.012	
D	4.80	5.20	0.189	0.205	
Е	3.75	4.05	0.148	0.159	
е	1.2	27	0.05		
HE	5.70	6.30	0.224	0.248	
L1	0.50	0.70	0.02	0.028	
Lp	0.65	0.85	0.026	0.033	
х	0.15		0.006		
у	0.	10	0.0	004	

DIM	MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
b2	_	0.65	_	0.026
e1	5.15		0.2	203
l1	_	1.15	_	0.045

Dimension in mm/inches

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JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	CI ACCIII
CLASSIV	CLASSIII	CLASSⅢ	CLASSIII

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 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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